

AAP Gen 7 (TO-240AA) Power Modules Schottky Rectifier, 200 A



PRIMARY CHARACTERISTICS			
I _{F(AV)} 200 A			
V_{R}	45 V		
Package	AAP Gen 7 (TO-240AA)		
Circuit configuration	Two diodes doubler circuit		

MECHANICAL DESCRIPTION

The AAP Gen 7, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation
- · Low thermal resistance
- UL approved file E78996
 - . **77**
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- · Easy mounting on heatsink

ELECTRICAL DESCRIPTION / APPLICATIONS

The VS-VSKDS401.. Schottky rectifier doubler has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	200	A		
V _{RRM}		45	V		
I _{FSM}	t _p = 5 μs sine	29 000	A		
V _F	100 A _{pk} , T _J = 125 °C	0.52	V		
T _J	Range	-55 to +175	°C		

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-VSKDS401/045	UNITS
Maximum DC reverse voltage	V_{R}	45	V
Maximum working peak reverse voltage	V_{RWM}	43	V



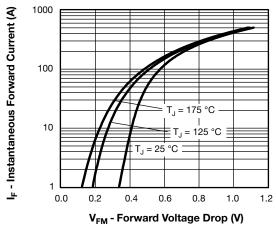
ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T _C = 120 °C, rectangular waveform		200	
Maximum peak one cycle	l	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	29 000	Α
non-repetitive surge current	IFSM	10 ms sine or 6 ms rect. pulse		3450	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 24 A, L = 1 mH		270	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5$ x V_R typical		40	Α

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum famound up be an advan		200 A	T _J = 25 °C	0.72	
		400 A		0.98	V
Maximum forward voltage drop	V_{FM}	200 A	T _J = 125 °C	0.69	
		400 A		0.96	
Maximum vayayaa laakaga ayyyaat	I _{RM}	T _J = 25 °C	V _R = Rated V _R	20	A
Maximum reverse leakage current		T _J = 125 °C		180	mA
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		10 300	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		5.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs
Maximum RMS insulation voltage	V _{INS}	50 Hz		3000 (1 min) 3600 (1 s)	V

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +175	°C	
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	0.26	°C/W	
Typical thermal resistance, case to heatsink per module		R _{thCS}		0.1	C/W	
Approximate weight				75	g	
Approximate weight				2.7	oz.	
Mounting torque ± 10 %	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the	4	Nm	
	busbar		spread of the compound.	3	INIII	
Case style			JEDEC®	TO-240AA co	mpatible	

www.vishay.com

Vishay Semiconductors



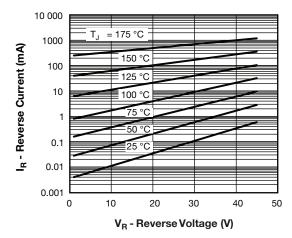


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

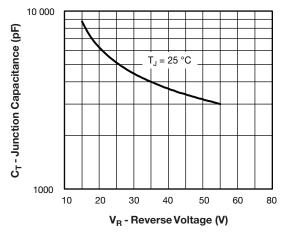


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

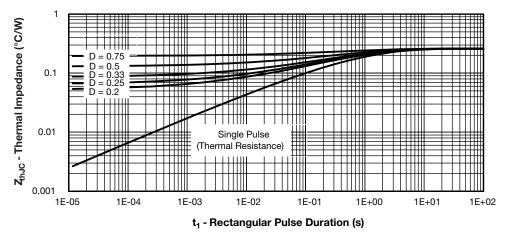


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

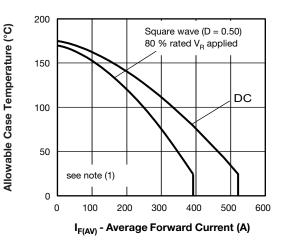


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

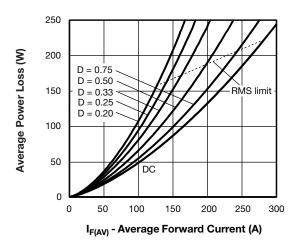


Fig. 6 - Forward Power Loss Characteristics

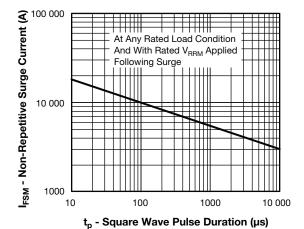


Fig. 7 - Maximum Non-Repetitive Surge Current

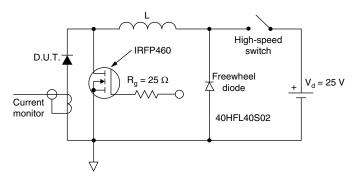
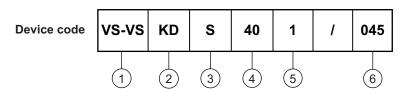


Fig. 8 - Unclamped Inductive Test Circuit

Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

ORDERING INFORMATION TABLE



1 - VS-VS = Vishay Semiconductors product

2 - Circuit configuration:

KD = ADD-A-PAK - 2 diodes doubler circuit

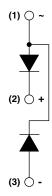
3 - S = Schottky diode

Average rating (x 10)

5 - Product silicon identification

6 - Voltage rating (045 = 45 V)

CIRCUIT CONFIGURATION

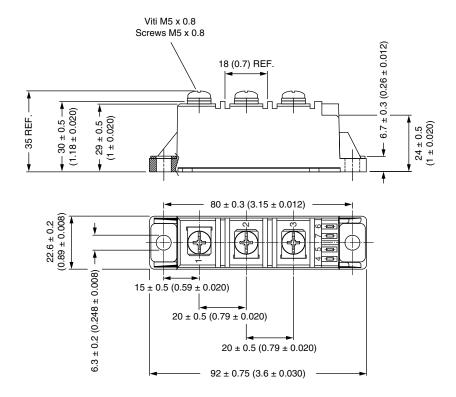


LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95369		



ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)





Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.